
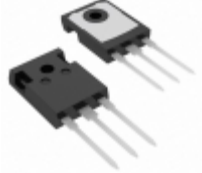

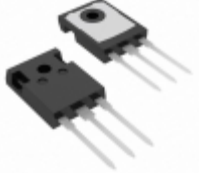



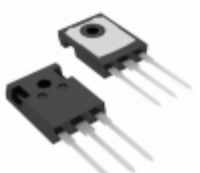

	<h2 style="color: red;">FDH50N50</h2>
	<p>Hersteller-Teilenummer: FDH50N50</p> <hr/> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 500V 48A TO-247</p> <hr/> <p>Datenblätter:  FDH50N50.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 30198 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FDH50N50
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 500V 48A TO-247
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	30198 pcs Stock
Serie	UniFET™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-247-3
Supplier Device-Gehäuse	TO-247
Verlustleistung (max)	625W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	48A (Tc)
Rds On (Max) @ Id, Vgs	105 mOhm @ 24A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	137nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	6460pF @ 25V
Verpackung	Tube





FDH50N50 ist neu im Original, Suche FDH50N50 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FDH50N50 Fairchild/ON Semiconductor mit Garantie und Vertrauen.
Anfrage FDH50N50: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FDH45N50F_F133 Fairchild/ON Semiconductor MOSFET N-CH 500V 45A TO-247</p>	 <p>FDH45N50F FAIRCHI FDH45N50F FAIRCHI</p>	 <p>FDH44N50 Fairchild/ON Semiconductor MOSFET N-CH 500V 44A TO-247</p>	 <p>FDH50N50 AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 48A TO-247</p>
 <p>FDH5500 Fairchild/ON Semiconductor MOSFET N-CH 55V 75A TO-247</p>	 <p>FDH50N50-F133 AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 48A TO-247</p>	 <p>FDH5500-F085 AMI Semiconductor / ON Semiconductor MOSFET N-CH 55V 75A TO-247</p>	 <p>FDH5500 AMI Semiconductor / ON Semiconductor MOSFET N-CH 55V 75A TO-247</p>

heiße Teile

Mehr

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 FDH038AN08A1	 FDH047AN08A0	 FDH047AN08A0	 FDH047AN08AO	 FDH055N15A
 FDH055N15A	 FDH15N50	 FDH15N50	 FDH210AN08	 FDH210N08
 FDH210N08	 FDH27N50	 FDH27N50	 FDH300A.TR	 FDH3369C
 FDH44N50	 FDH44N50	 FDH45N50F	 FDH50N50	 FDH50N50_F133
 FDH5500_F085	 IRLR8203TRRPBF	 L4940D2M5-TR	 LT1947EMS#PBF	 LT6654AHS6-4.096#PBF
 M25PE10-VMP6TG	 M505045F	 P840A7901	 PA75S48-28	 R1EX24128ASASOA
 RY611012	 S-93C56BDOH-0001	 SI4174DY-T1-E3	 Si4532CDY-T1-E3	 SM3023NSUC-TRG
 SMCJ12CA-E3	 UFM500-P	 V24B12T200BS	 V300B3V3H150A	 WPT310-18

Contact us: Info@Y-IC.com

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